# 2SK1612

### Silicon N-Channel Power F-MOS FET

#### ■ Features

• High avalanche energy capacity

● V<sub>GSS</sub>: 30V guaranteed

lacktriangle Low  $R_{DS(on)}$ , high-speed switching characteristic

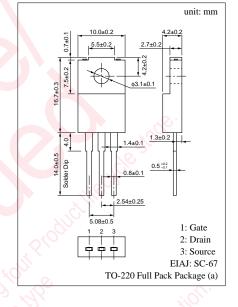
#### ■ Applications

• High-speed switching (switching power supply)

• For high-frequency power amplification

### ■ Absolute Maximum Ratings $(T_C = 25^{\circ}C)$

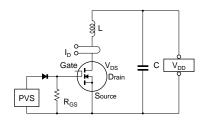
Parameter		Symbol	Ratings	Unit	
Drain to Source breakdown voltage		V <sub>DSS</sub>	800	V	
Gate to Source voltage		V <sub>GSS</sub>	±30	V	
Drain current	DC	$I_D$	±3	A	
	Pulse	$I_{DP}$	±6	A	
Avalanche energy capacity		EAS*	20	mJ	
Allowable power	$T_C = 25^{\circ}C$	n	50	337	
dissipation	Ta = 25°C	$P_{D}$	2	W	
Channel temperature		$T_{ch}$	150	°C	
Storage temperature		$T_{\rm stg}$	-55 to +150	°C	



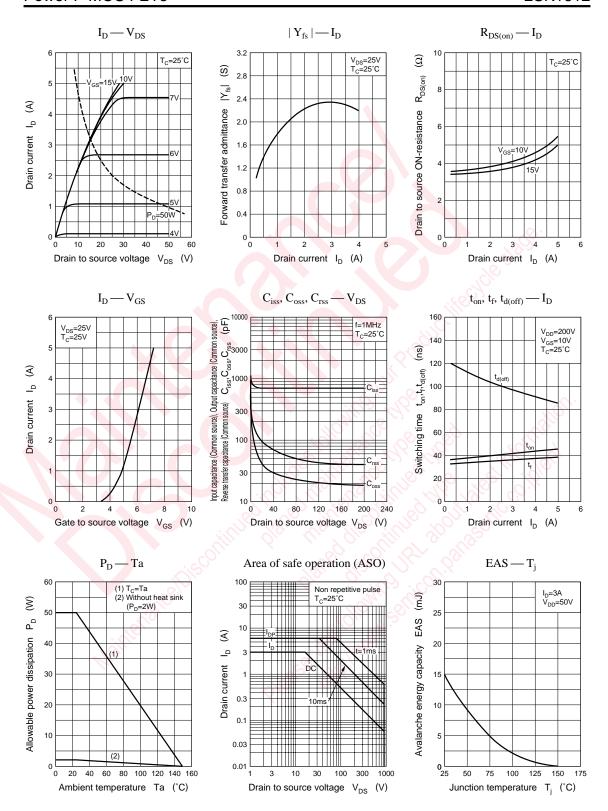
## ■ Electrical Characteristics (T<sub>C</sub> = 25°C)

Parameter	Symbol	Conditions	min	typ	max	Unit
Drain to Source cut-off current	$I_{DSS}$	$V_{DS} = 720V, V_{GS} = 0$	J. "	6 ×6	0.1	mA
Gate to Source leakage current	$I_{GSS}$	$V_{GS} = \pm 30V, V_{DS} = 0$	1, 7,131	100	±1	μΑ
Drain to Source breakdown voltage	$V_{\rm DSS}$	$I_D = 1 \text{mA}, V_{GS} = 0$	900	977, 4		V
Avalanche energy capacity	EAS*	$L = 3.4$ mH, $I_D = 3$ A, $V_{DD} = 50$ V	15			mJ
Gate threshold voltage	V <sub>th</sub>	$V_{DS} = 25V$ , $I_D = 1mA$	1	3//	5	V
Drain to Source ON-resistance	R <sub>DS(on)</sub>	$V_{GS} = 10V, I_D = 2A$		3.8	5	Ω
Forward transfer admittance	Y <sub>fs</sub>	$V_{DS} = 25V$ , $I_D = 2A$	1.5	2.2		S
Input capacitance (Common Source)	C <sub>iss</sub>	$V_{DS} = 20V, V_{GS} = 0, f = 1MHz$	(S),	730		pF
Output capacitance (Common Source)	C <sub>oss</sub>			90		pF
Reverse transfer capacitance (Common Source)	C <sub>rss</sub>	jis In		40		pF
Turn-on time	t <sub>on</sub>	V 10V 10 04 VO.		40		ns
Fall time	$t_{\rm f}$	$V_{GS} = 10V, I_D = 2A$		35		ns
Turn-off time (delay time)	t <sub>d(off)</sub>	$V_{DD} = 200V, R_L = 100\Omega$		105		ns

<sup>\*</sup> Avalanche energy capacity test circuit



<sup>\*</sup> Single pulse



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